

A PROTOTYPE HYBRID PIXEL DETECTOR ASIC FOR THE CLIC EXPERIMENT

Pierpaolo Valerio

Outline

□ The CLIC project

CLICpix design

CLICpix prototype characterization

Conclusions

Outline

□ The CLIC project

□ CLICpix design

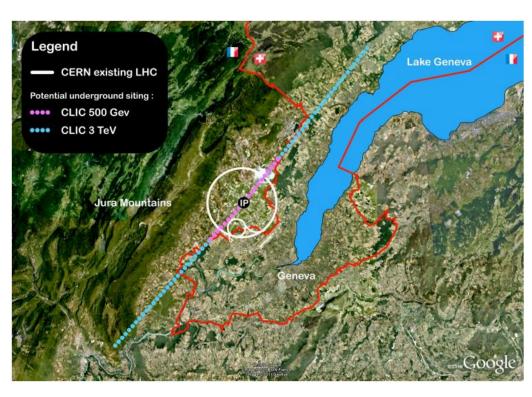
CLICpix prototype characterization

Conclusions

The CLIC project

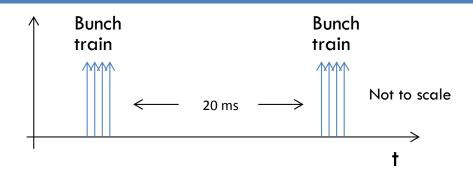
The Compact Linear Collider (CLIC) is a study for a high-energy and highluminosity collider

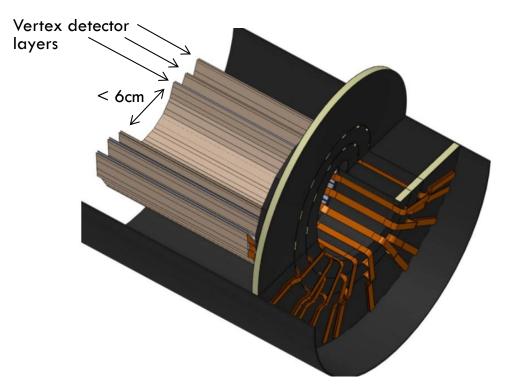
- □ e⁺e⁻ collider
- Can be used to determine standard model parameters with a higher precision than proton colliders
- Allows the detection of new particles and the testing of models as supersymmetry and Higgs strong interactions
- \square 3 TeV \rightarrow 48 km long!



The CLIC beam

- Bunch crossings every0.5 ns in trains of156 ns
- □ Bunch trains every 20ms → small dutycycle
- □ Air cooling → low power consumption





Timing requirements

- □ 312 bunch crossings in 156 ns and a high background rate → Event timestamp
- □ Time of Arrival measurement with 10 ns accuracy is required to discriminate tracks

- □ High spatial (sub-pixel) resolution → Charge measurement
- At least 4-bit Time-over-Threshold is needed

□ The CLIC project

CLICpix design

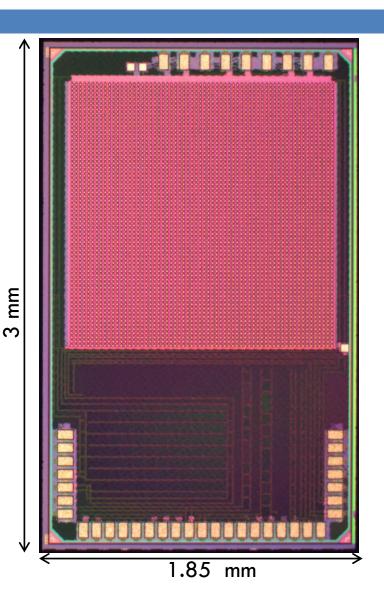
CLICpix prototype characterization

Conclusions

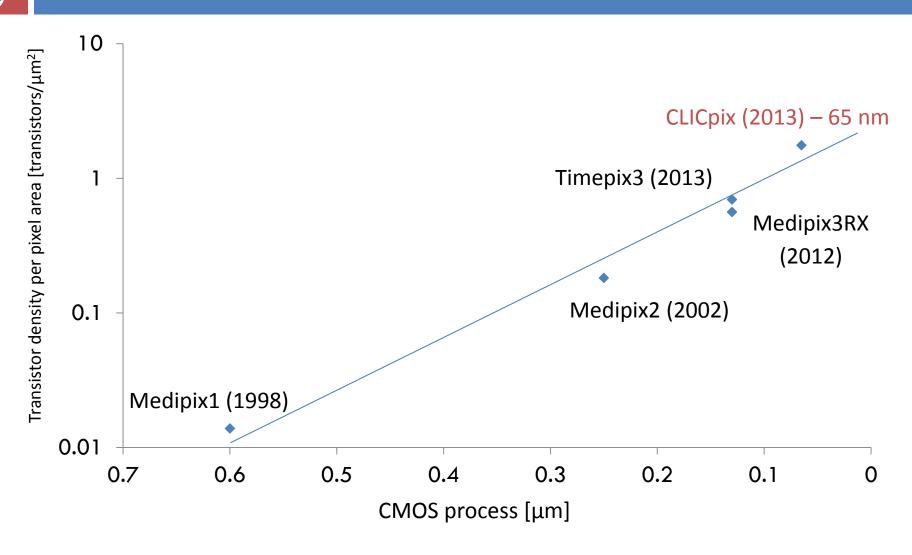
CLICpix

- CLICpix is a hybrid pixel detector to be used as the CLIC vertex detector
- Main features:
 - \square small pixel pitch (25 μ m),
 - Simultaneous TOA and TOT measurements
 - Power pulsing
 - Data compression
- A demonstrator of the CLICpix architecture with an array of 64x64 pixels has been submitted using a commercial 65 nm technology and tested
- The technology used for the prototype has been previously characterized and validated for HEP use and radiation hard design*

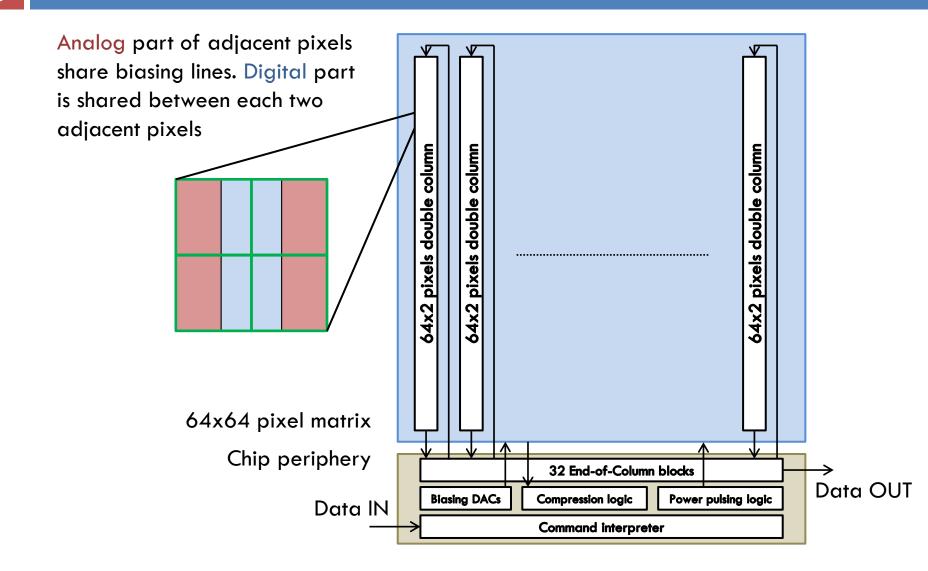
^{*}S. Bonacini, P. Valerio et al, Characterization of a commercial 65 nm CMOS technology for SLHC applications, Journal of Instrumentation, 7(01):P01015–P01015, January 2012



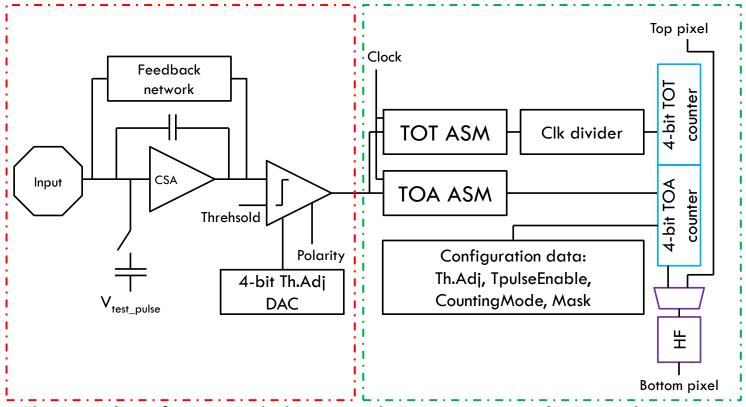
"Moore's law" for pixel detectors



A simple block diagram

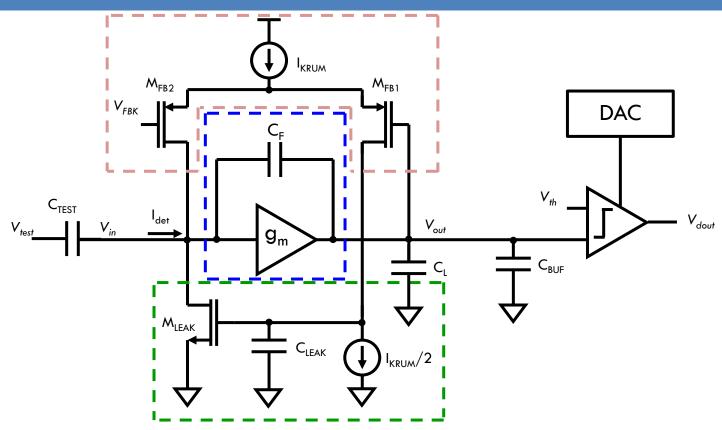


Pixel architecture



- The analog front-end shapes photocurrent pulses and compares them to a fixed (configurable) threshold
- Digital circuits simultaneously measure Time-over-Threshold and Time-of-Arrival of events and allow zero-compressed readout

Analog front-end diagram



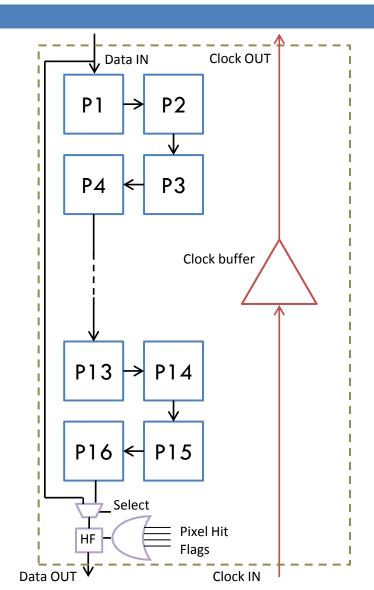
- The front-end uses the Krummenacher architecture, with a single ended preamp, a two-stage discriminator and a binary weighted 4-bit DAC for threshold equalization
- Switches are included to handle pulses of both polarities and to disconnect the test capacitor when it is not used

Pixel logic summary

Technology	65 nm (High-Vt Standard Cells), Asynchronous State Machines	
Pixel size	25x25 μm - 25x14 μm (Analog) - 25x11 μm (Digital)	
Acquired Data	TOT and TOA	
Counter Depth (LFSR)	4 bits TOT + 4 bits TOA (or counting, for calibration)	
Target Clock Speed	100 MHz (acquisition) 320 MHz (readout)	
Data type	Full Frame Zero compression (pixel, superpixel and column skipping)	
Acquisition Type	Non-continuous	
Power Saving	Clock gating (digital part), Power gating (analog part)	

Super-Pixels

- In CLICpix, pixels are clustered in 2x8 arrays (Super-Pixels)
- Area reduction because some of the electronics can be shared (clock distribution tree, biasing lines)
- Additional compression layer
- The clock is distributed along each column exploiting the delays of buffers to give each pixel a clock signal with a different phase

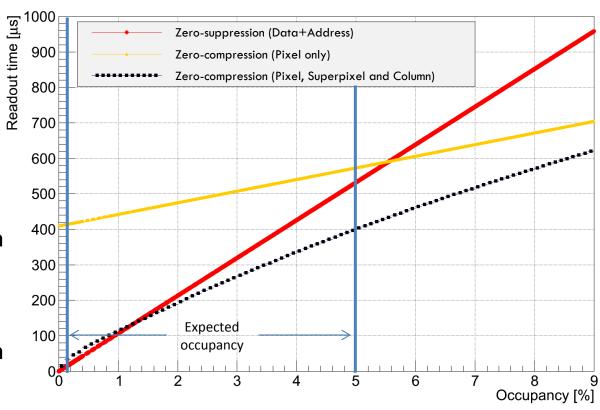


Data compression

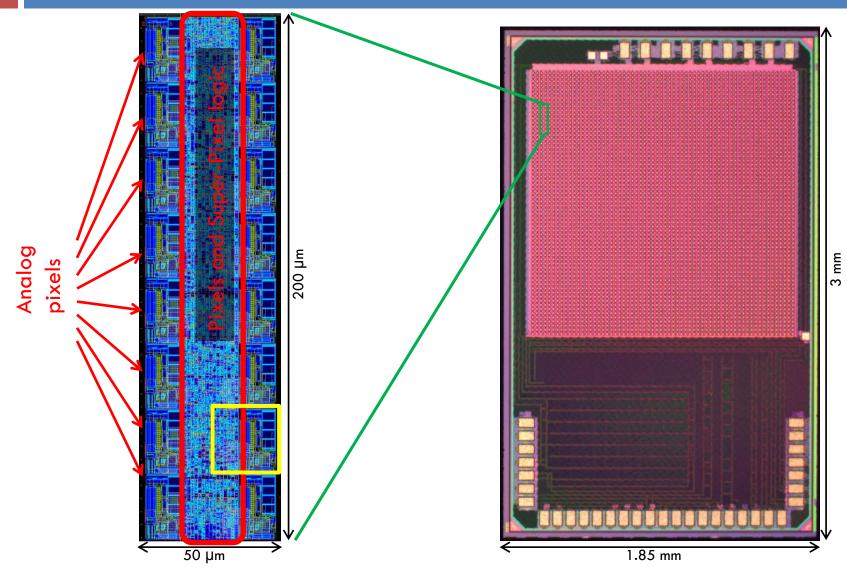
- Two different compression schemes were evaluated
- Zero-suppression
 - Only pixels with data are read out
 - Data have an address associated to it
- Zero-compression
 - All pixels are read out
 - Pixels have a "hit-flag" bit allowing to skip data stored in pixels which were not hit
 - Additional compression layers (superpixels, columns)
 can be added

Readout Architecture Comparison

- Readout time for different architectures have been compared.
- 320MHz readout clock (DDR)
- Packet-based readout (red line), zero-compression with pixel, superpixel and column skipping (dotted black line), zero-compression with only pixel skipping (yellow line)



Super-Pixel Layout



Periphery and end-of-column

- A periphery logic with a command register is implemented to control all the features of the chip
- Columns are read serially and programmed in parallel
- DACs to generate reference voltages are included. An external absolute voltage reference is needed due to the lack of a band-gap block.
- A power pulsing and clock gating scheme has been implemented allowing to reduce the average power consumption to less than 50 mW/cm² (allowing the use of air cooling)

Outline

□ The CLIC project

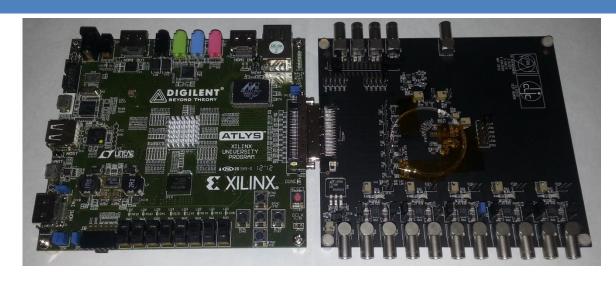
□ CLICpix design

CLICpix prototype characterization

Conclusions

Functional tests

Using a test setup with an FPGA development board, automated tests could be programmed

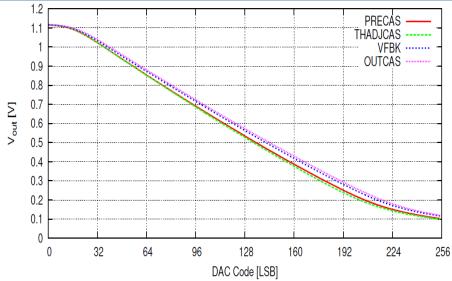


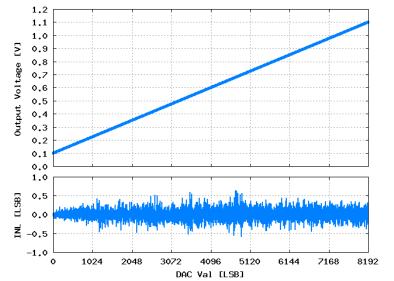
All the chip features were tested successfully:

- Configuration data can be sent to the pixel matrix and read back correctly
- Pixel configuration (calibration DAC code, pixel masking, test pulse injection)
 works
- Test pulses can be injected to selected pixels and TOT and TOA counters work
- Zero compressed acquisition and readout routines produce the expected result and the output stream can be decoded correctly

Periphery blocks tests

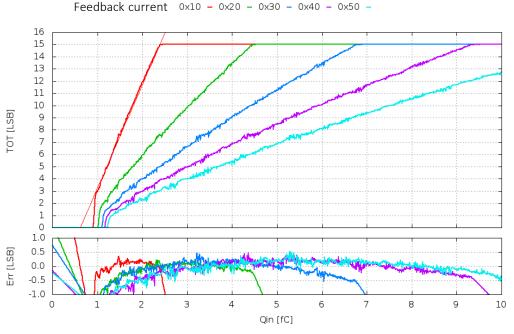
- Periphery DACs were tested
- Their characteristics were found to be consistent with simulations within the uncertainties due to process variations
- The variation of power consumption changing the biasing currents of analog blocks was measured and it matched expected values
- The power pulsing control system works according to specifications reducing the power consumption by more than one order of magnitude
- The power-on and power-off times can be programmed
- The front-end wake-up time is less than
 15 µs

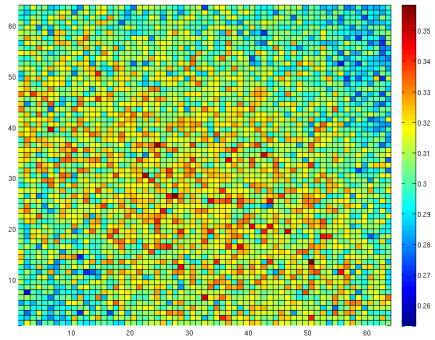




TOT measurements

- □ TOT gain variation is 4.2% r.m.s.
- Tested for nominal feedback current
- Corners have lower TOT gain

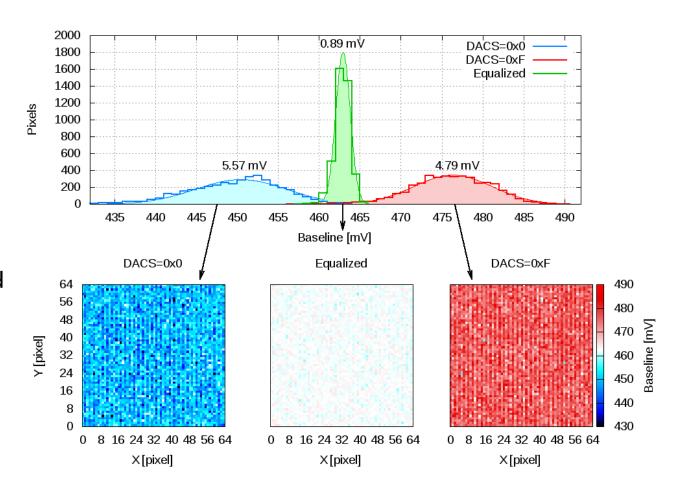




- TOT integral non-linearity for different feedback currents was tested
- TOT dynamic range matches simulations

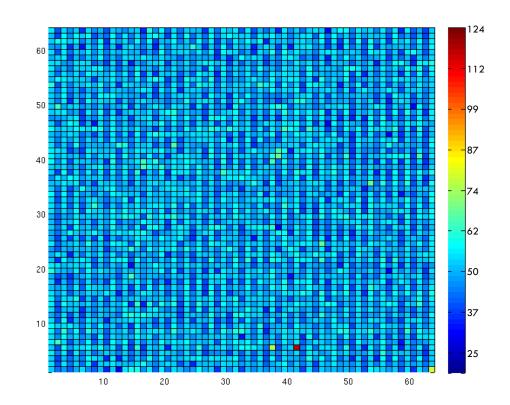
Threhsold equalization

- Routines for equalizing the threshold using the pixel calibration DACs were implemented, finding the noise floor for all pixels
- Calibrated spread is 0.89 mV (about 22 e⁻ assuming a 10 fF test capacitance) across the whole matrix



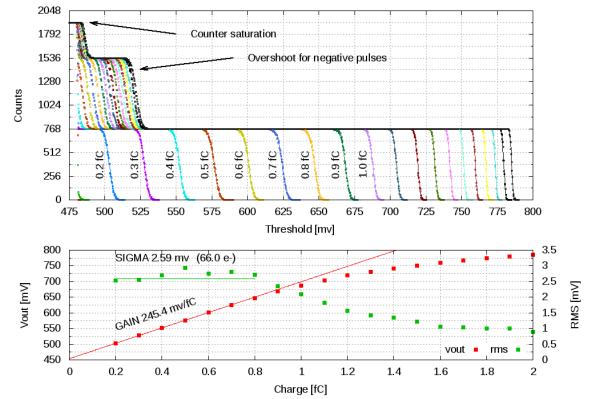
Noise characterization

- Threshold scans through the baseline voltage were used to calculate the noise floor
- There is a small pattern
 effect due to the different
 routing of pixels in the
 double columns
- Average noise is 1.96 mV r.m.s. (about 51 e⁻ assuming a 10 fF test capacitance)

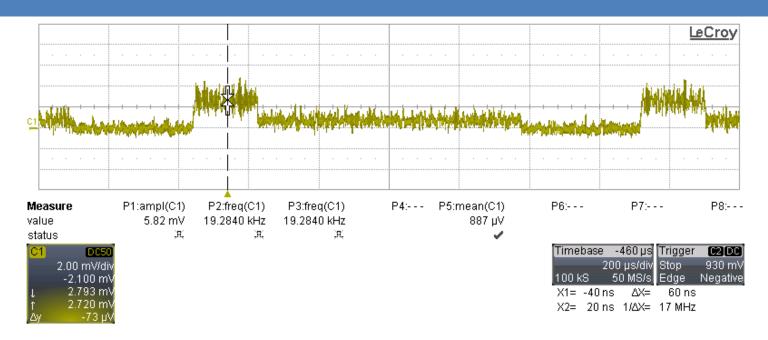


Other analog tests

- Noise and gain measurements were performed on some pixels injecting test pulses, with results closely matching simulations
- Results are to be considered preliminary, noise sources are being investigated



Digital power consumption



- Change in power consumption between acquisition, readout and idling can be seen
- Total power consumption of the digital part is lower than 4 mW during readout
- Average power consumption of the digital part is lower than 1 mW

Measurement summary

	Simulations	Measurement
Rise time	50ns	
TOA Accuracy	< 10 ns	< 10 ns
Gain	44 mV/ke ⁻	40 mV/ke ⁻
Dynamic Range	up to 40 ke ⁻ (configurable)	up to 40 ke ⁻ (configurable)
Non-Linearity (TOT)	< 8% at 40 ke ⁻	< 4% at 40 ke ⁻
Equivalent Noise (no sensor capacitance)	~60 e ⁻	~51 e ⁻ (with 10% variation r.m.s.)
DC Spread (uncalibrated)	$\sigma = 160 e^{-}$	$\sigma = 128 e^{-}$
DC Spread (calibrated)	$\sigma = 24 e^{-}$	$\sigma = 22 e^{-}$
Analog pixel power consumption (while ON)	6.5 μW	7 μW

Measurements
expressed in
electrons depend
on capacitance
values. A nominal
value of 10 fF was
assumed here for
the test capacitor

Outline

□ The CLIC project

□ CLICpix design

CLICpix prototype characterization

Conclusions

Conclusions

- A CLICpix prototype has been designed, fabricated and tested (characterization is still ongoing) using a commercial 65 nm CMOS technology
- Main features include 25 µm pixel pitch, simultaneous ToT and ToA measurements and power pulsing capabilities
- Measurements closely match simulations
- Ideas implemented and tested on this prototype can be used in future projects

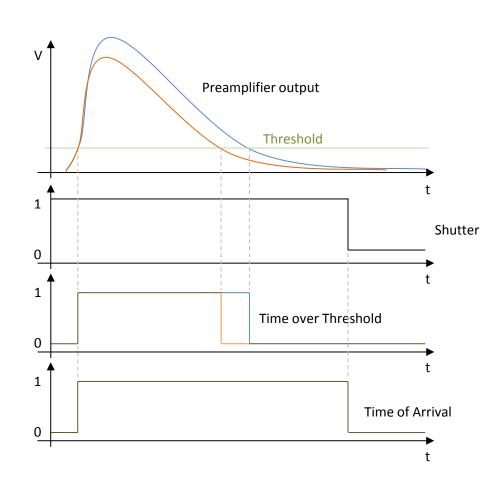
Thanks for your attention

Thanks to J. A. Alozy, S. Arfaoui, R. Ballabriga Sune, M. Benoit, S. Bonacini, M. Campbell, D. Dannheim, M. De Gaspari, D. Felici, S. Kulis, X. Llopart Cudie, A. Nascetti, S. Poikela, W. Wong

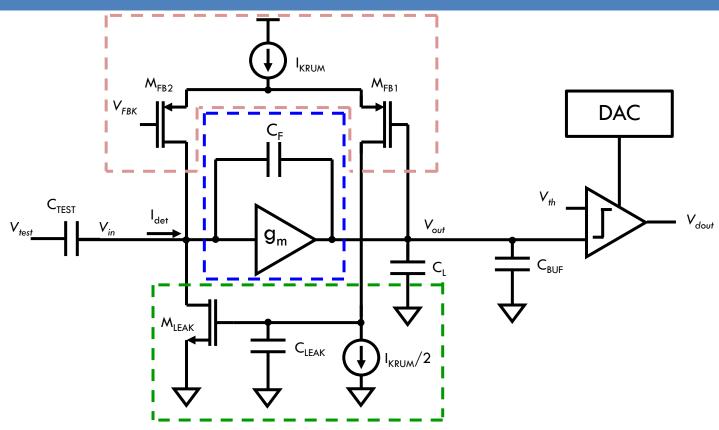
Backup Slides

Timing measurements

- Time over Threshold measures the time the input pulse stays over a fixed threshold
 - It is directly proportional to the amount of charge deposited by a particle and thus its energy
- Time of Arrival measures the relative time in which the pulse was acquired
 - It is used to identify different particle tracks in a noisy background

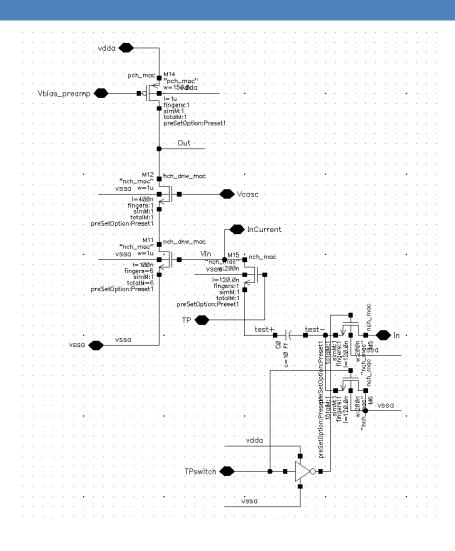


Pixel block diagram

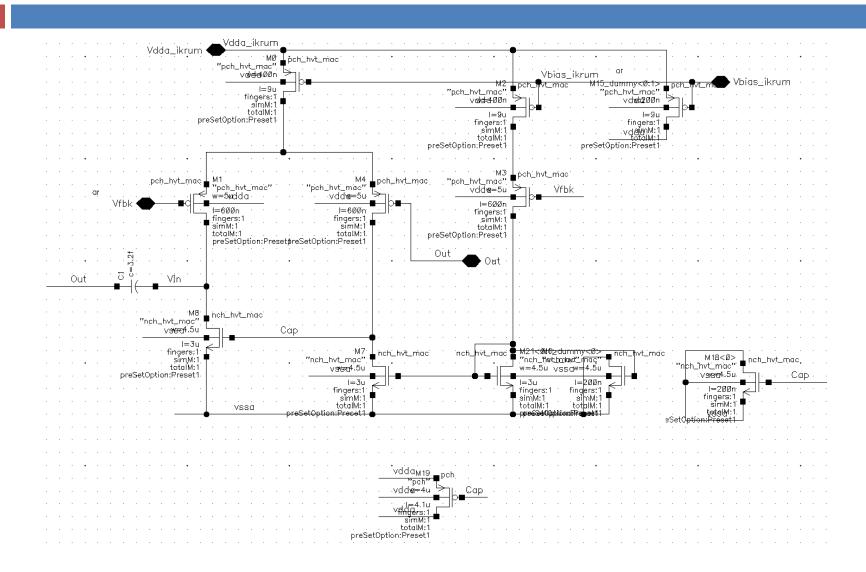


- The front-end uses the Krummenacher architecture, with a single ended preamp, a two stage discriminator and a 4-bit DAC
- Switches are included to handle pulses of both polarities and to disconnect the test capacitor when it is not used

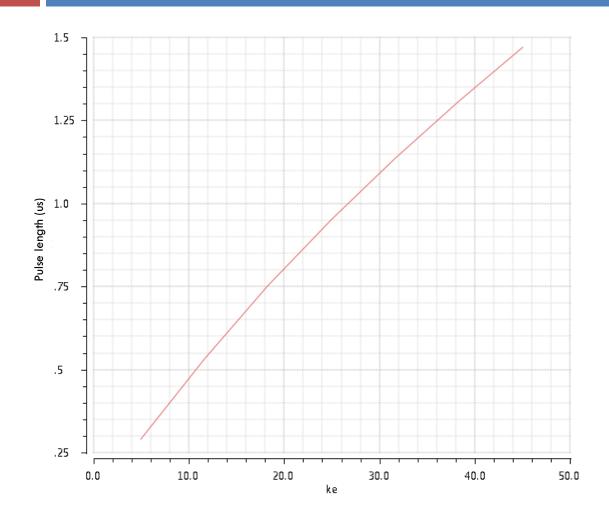
Premplifier schematic



Feedback network schematic

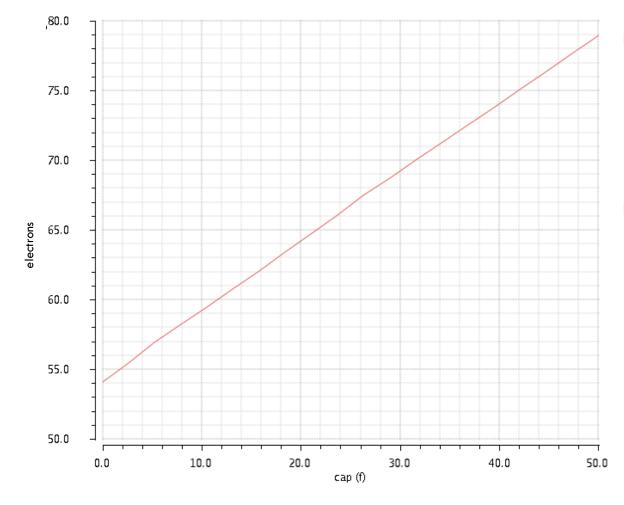


TOT linearity



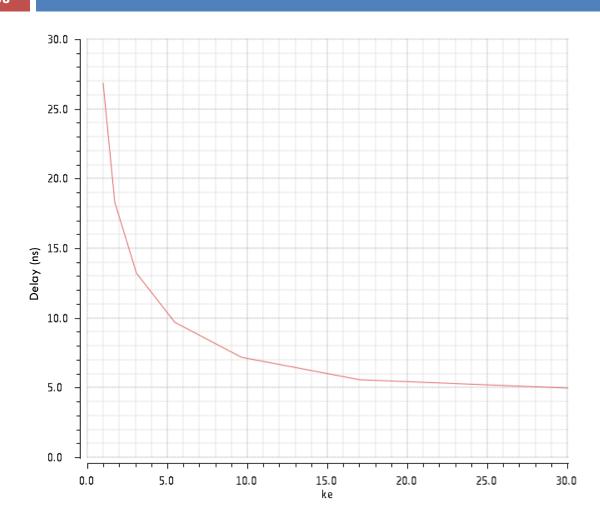
- The frontend has a linear TOT throughout all its the dynamic range (amplitude saturates with much lower charges)
- Uncertainty in the TOT count (mainly due to mismatch of the lkrum mirror) is limited to one LSB of the counter

ENC (as a function of input C)



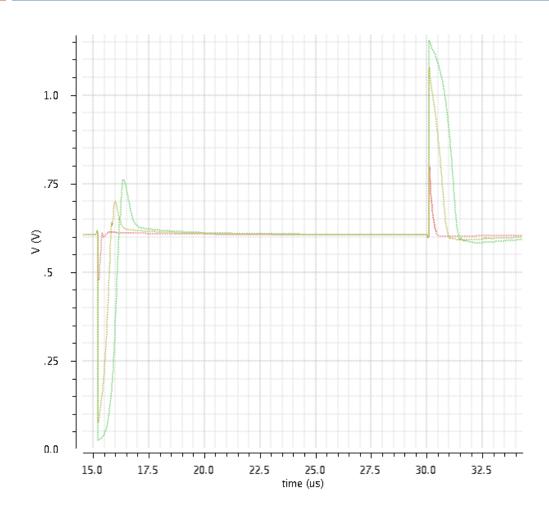
- The capacitances of the pad and the frontend are already included as part of the extracted parasitics
- The frontend show a linear increse of the rms noise by increasing the detector/bonding capacitance

Time walk



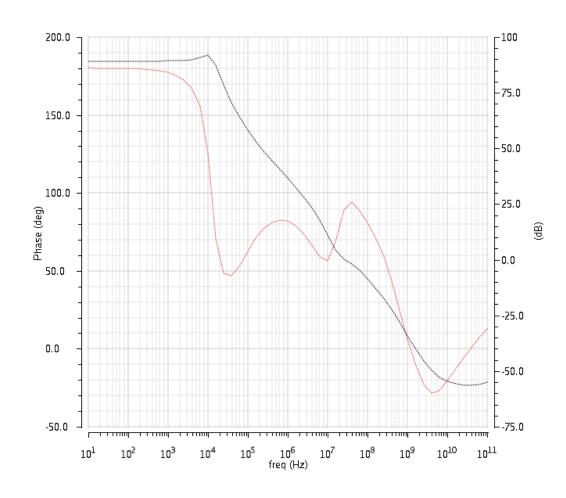
- The time walk is reduced for high input charges
- Low charge inputs can produce pulses with a TOT count of 0. The TOT LSB is 2.8 ke⁻.
- The TOA can be corrected by using the TOT information. Two or three bins are enough to have a 10 ns resolution for all input pulses but those the with a TOT of 0.

Polarity effect



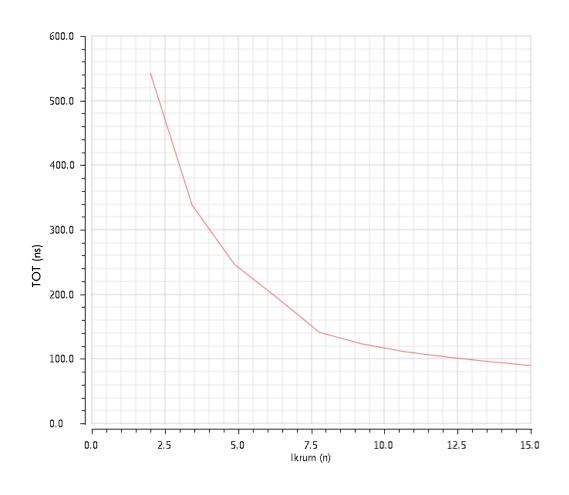
- The front-end produces pulses with a different shape for different input polarities
- The effect is due to having a small compensation capacitor (for area issues)
- Pulses with different polarities but same energy will give different TOT measurements. This can be compensated by changing the lkrum value

Front-end stability



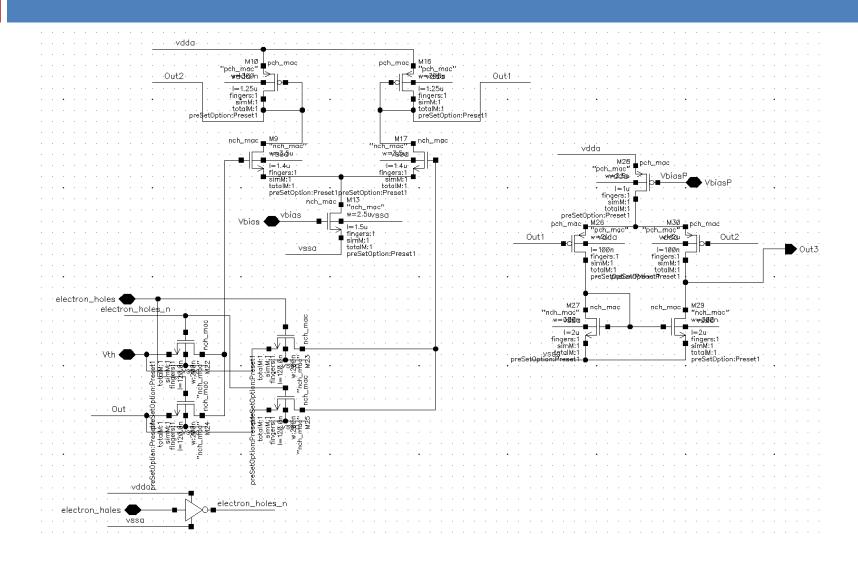
- Open-loop Bode
 diagram was
 simulated (including
 parasitics) opening the
 circuit at the input of
 the preamplifier
- Phase margin is approx. 50 deg

Effect of Ikrum on TOT

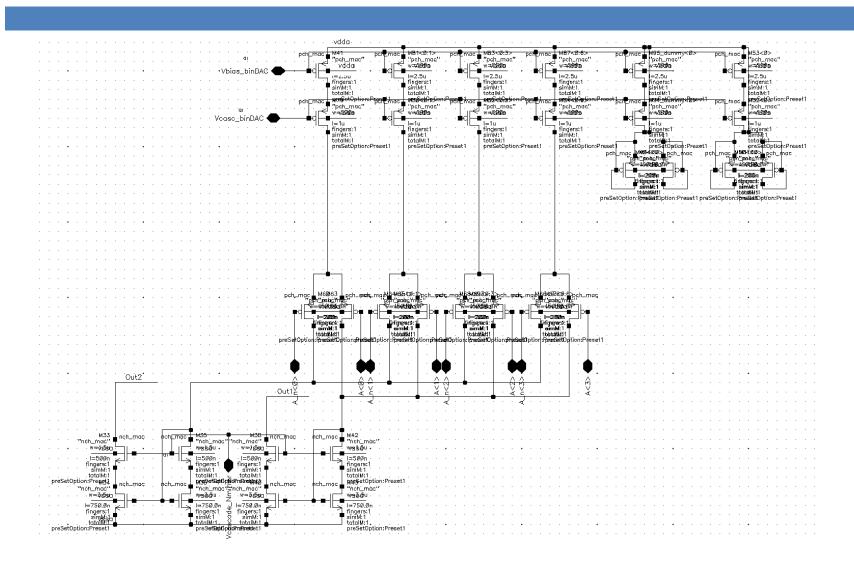


The plot shows the effect of lkrum on the TOT for a 5 ke⁻ pulse.

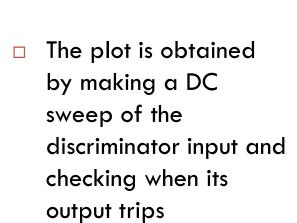
Discriminator schematic



Calibration DAC schematic



Threshold variation due to DAC output



Name

VS("/Out")

VS("/Out")

VS("YOut")

VS("/Out")

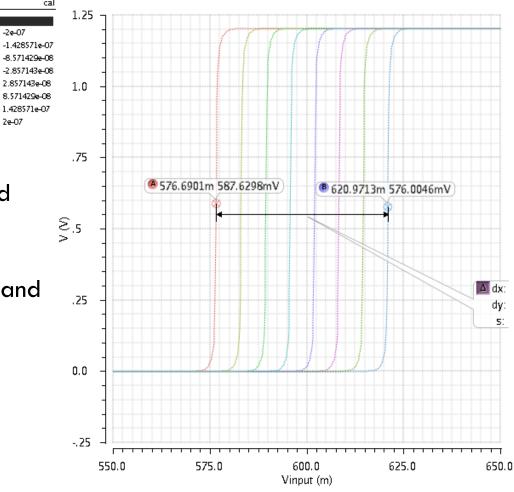
VS("/Out")

VS("/Out") VS("/Out")

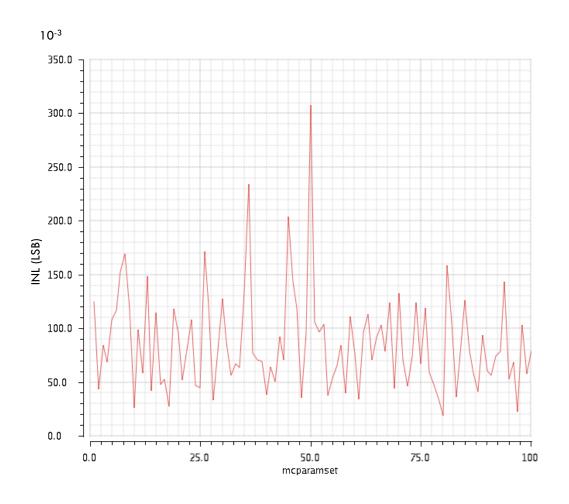
VS("/Out")

-2e-07

1.428571e-07 2e-07

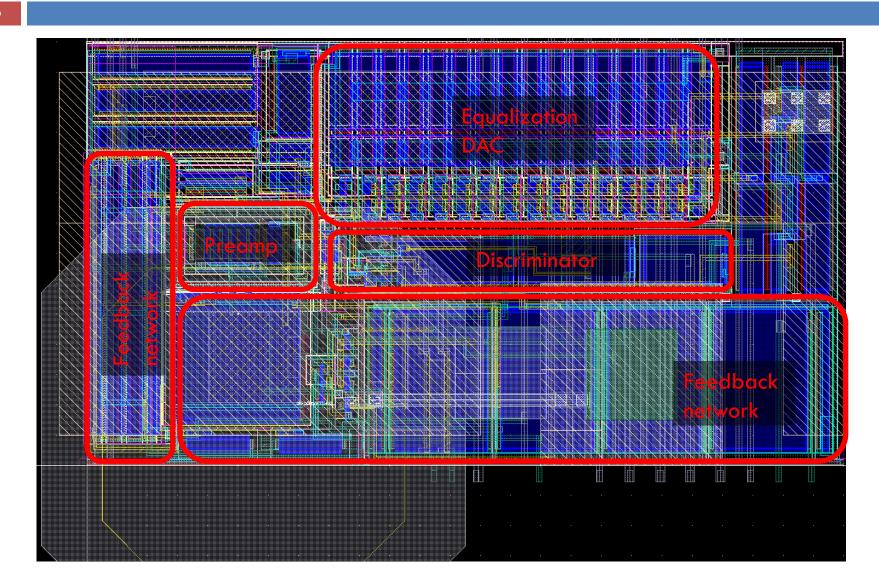


Equalization DAC INL



INL of the DAC was simulated using
 Montecarlo simulations with mismatch models
 (Montecarlo runs with process variations are not possible with TSMC PDK).

Analog Pixel Layout

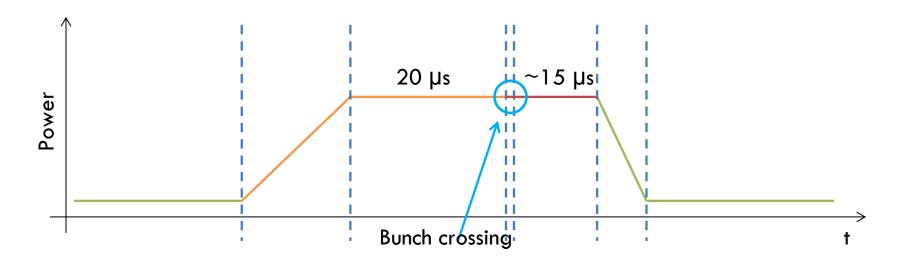


Power pulsing

- The specific application of the chip requires a very low duty cycle (the chip will acquire data for 156 ns every 20 ms), leaving the possibility to periodically turn off and on parts of the chip
- The main contribution to the power consumption is the analog front-end, which would use $\sim 2W/cm^2$ if run continuously.
- A power pulsing scheme has been implemented allowing to reduce the average power consumption to less than 50 mW/cm² (allowing the use of air cooling)
- In order to make the requirements for the power supply more relaxed, each column can be turned on at a different time to gradually turn on and off the chip
- Power pulsing is activated by an external signal and it switches the biasing of the structures which use the most power to a low-power state. During this power saving state the analog power can be switched off entirely

Power pulsing

- The specific application of the chip requires a very little duty cycle (the chip will acquire data for 156 ns every 20 ms), leaving the possibility to periodically turn off and on parts of the chip
- The analog part of the pixel uses too much power by itself. It's necessary to implement a controlled power down when the chip is not acquiring data
- In order to make the requirements for the power supply more relaxed, each column can be turned on at a different time to gradually turn on each chip



End-of-column functionality

- One end-of-column per each two columns (as they share the digital part)
- □ The functionalities of the block are managing the clock gating, keep track of the data during readout and provide the array with configuration data.
- The readout of the chip is done serially, one "double column" at a time. Each pixel shifts the data to the next one making the counters work as a long shift register, using a fast readout clock (320 MHz)
- The counters are connected together (and to the pixels directly above and below) to act as a single shift register during the data readout phase.
- Each end-of-column has a state machine that counts the number of pixels being read out (with multiple counters, taking into account skipped pixels and skipped clusters) to be able send a start-reading signal to the next column

Other analog tests

